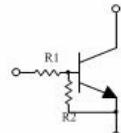


## Small Signal Diode

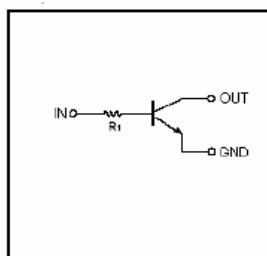
### Features

- ◊ Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistor (see equivalent circuit).
- ◊ The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- ◊ Only the on/off conditions need to be set for operation, making device design easy.
- ◊ Green compound (Halogen free) with suffix "G" on packing code and prefix "G" on date code.

### DTC114 TM/TE/TUA/TCA/TSA NPN Small Signal Transistor



**equivalent circuit**



### Ordering Information

Package	Part No.	Packing	Marking
SOT-723	DTC114 TM	8K / 7" Reel	04
SOT-523	DTC114 TE	3K / 7" Reel	04
SOT-323	DTC114 TUA	3K / 7" Reel	04
SOT-23	DTC114 TCA	3K / 7" Reel	04
TO-92S	DTC114 TSA	3K / 7" Reel	

### Maximum Ratings and Electrical Characteristics

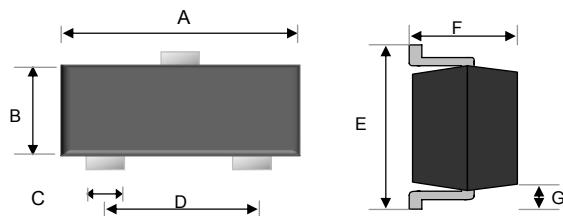
Rating at 25°C ambient temperature unless otherwise specified.

Type Number	Symbol	Value					Units
		TM	TE	EUA	ECA	ESA	
Power Dissipation	PD	100	150	200		300	mW
Collector-Base Voltage	$V_{CBO}$			50			V
Collector-Emitter Voltage	$V_{CEO}$			50			V
Emitter-Base Voltage	$V_{EBO}$			5			V
Collector Current -Continuous	$I_C$			100			mA
Junction and Storage Temperature Range	$T_J, T_{STG}$			-55 to + 150			°C

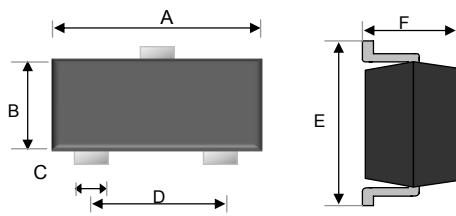
Notes:1. Valid provided that electrodes are kept at ambient temperature

Parameter	Symbol	Min	Typ	Max	Condition	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	50			$I_C=50\mu A, I_E=0$	V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	50			$I_C=1mA, I_B=0$	V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	5			$I_E=50\mu A, I_C=0$	V
Collector cut-off current	$I_{CBO}$			0.5	$V_{CB}=50V, I_E=0$	$\mu A$
Emitter cut-off current	$I_{EBO}$			0.5	$V_{EB}=4V, I_C=0$	$\mu A$
DC Current Gain	$h_{FE}$	100	300	600	$V_{CE}=5V, I_C=1mA$	
Collector-emitter saturation voltage	$V_{CE(sat)}$			0.3	$I_C=10mA, I_B=1mA$	V
Transition frequency	$f_T$	250			$V_{CE}=10V, I_E=-5mA, f=100MHz$	MHz
Input resistor	$R_1$	7	10	13		KΩ

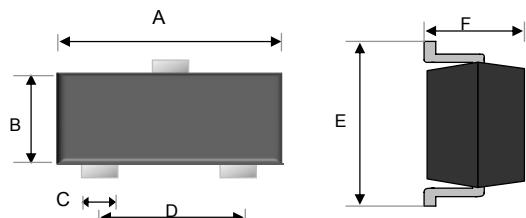
SOT-23



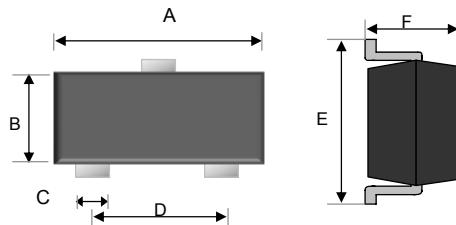
SOT-323



SOT-523



SOT-723



Dimensions	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	1.50	1.70	0.06	0.07
B	0.70	0.80	0.03	0.03
C	0.25	0.35	0.01	0.01
D	0.90	1.10	0.04	0.04
E	1.50	1.70	0.06	0.07
F	0.70	0.90	0.03	0.04

Dimensions	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
A	1.15	1.25	0.05	0.05
B	0.75	0.85	0.03	0.03
C	0.17	0.27	0.01	0.01
D	0.8 TYP		0.31 TYP	
E	1.15	1.25	0.05	0.05
F			0.50	
				0.02

TO-92S

